

Ivan OhlÅ-dal

List of Publications by Year in descending order

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61
papers

871
citations

471509

17
h-index

526287

27
g-index

61
all docs

61
docs citations

61
times ranked

445
citing authors

#	ARTICLE	IF	CITATIONS
1	Optical characterization of inhomogeneous thin films with randomly rough boundaries. Optics Express, 2022, 30, 2033.	3.4	5
2	Characterization of randomly rough surfaces using angle-resolved scattering of light and atomic force microscopy. Journal of Optics (United Kingdom), 2021, 23, 105602.	2.2	4
3	Optics of Inhomogeneous Thin Films with Defects: Application to Optical Characterization. Coatings, 2021, 11, 22.	2.6	9
4	Determining shape of thickness non-uniformity using variable-angle spectroscopic ellipsometry. Applied Surface Science, 2020, 534, 147625.	6.1	6
5	Spectroscopic ellipsometry of inhomogeneous thin films exhibiting thickness non-uniformity and transition layers. Optics Express, 2020, 28, 160.	3.4	22
6	Optical quantities of a multilayer system with randomly rough boundaries and uniaxial anisotropic media calculated using the Rayleigh-Rice theory and Yeh matrix formalism. Physica Scripta, 2020, 95, 095503.	2.5	1
7	Ellipsometric characterization of inhomogeneous thin films with complicated thickness non-uniformity: application to inhomogeneous polymer-like thin films. Optics Express, 2020, 28, 36796.	3.4	4
8	Optical Characterization of Non-Stoichiometric Silicon Nitride Films Exhibiting Combined Defects. Coatings, 2019, 9, 416.	2.6	13
9	Optical characterization of inhomogeneous thin films containing transition layers using the combined method of spectroscopic ellipsometry and spectroscopic reflectometry based on multiple-beam interference model. Journal of Vacuum Science and Technology B: Nanotechnology and Microelectronics, 2019, 37, .	1.2	8
10	Optical properties of the crystalline silicon wafers described using the universal dispersion model. Journal of Vacuum Science and Technology B: Nanotechnology and Microelectronics, 2019, 37, 062907.	1.2	3
11	Approximations of reflection and transmission coefficients of inhomogeneous thin films based on multiple-beam interference model. Thin Solid Films, 2019, 692, 137189.	1.8	12
12	Combination of spectroscopic ellipsometry and spectroscopic reflectometry with including light scattering in the optical characterization of randomly rough silicon surfaces covered by native oxide layers. Surface Topography: Metrology and Properties, 2019, 7, 045004.	1.6	11
13	Efficient method to calculate the optical quantities of multi-layer systems with randomly rough boundaries using the Rayleigh-Rice theory. Physica Scripta, 2019, 94, 045502.	2.5	12
14	Approximate methods for the optical characterization of inhomogeneous thin films: Applications to silicon nitride films. Journal of Electrical Engineering, 2019, 70, 16-26.	0.7	4
15	Ellipsometry of Layered Systems. Springer Series in Surface Sciences, 2018, , 233-267.	0.3	5
16	Optical quantities of multi-layer systems with randomly rough boundaries calculated using the exact approach of the Rayleigh-Rice theory. Journal of Modern Optics, 2018, 65, 1720-1736.	1.3	9
17	Determination of thicknesses and temperatures of crystalline silicon wafers from optical measurements in the far infrared region. Journal of Applied Physics, 2018, 123, .	2.5	3
18	Use of the Richardson extrapolation in optics of inhomogeneous layers: Application to optical characterization. Surface and Interface Analysis, 2018, 50, 757-765.	1.8	15

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19	Different theoretical approaches at optical characterization of randomly rough silicon surfaces covered with native oxide layers. <i>Surface and Interface Analysis</i> , 2018, 50, 1230-1233.	1.8	7
20	Optical Characterization of Thin Films Exhibiting Defects. <i>Springer Series in Surface Sciences</i> , 2018, , 271-313.	0.3	4
21	Temperature-dependent dispersion model of float zone crystalline silicon. <i>Applied Surface Science</i> , 2017, 421, 405-419.	6.1	21
22	Optical characterization of randomly microrough surfaces covered with very thin overlayers using effective medium approximation and Rayleigh-Rice theory. <i>Applied Surface Science</i> , 2017, 419, 942-956.	6.1	21
23	Ellipsometric and reflectometric characterization of thin films exhibiting thickness non-uniformity and boundary roughness. <i>Applied Surface Science</i> , 2017, 421, 687-696.	6.1	13
24	Optical characterization of SiO ₂ thin films using universal dispersion model over wide spectral range. <i>Proceedings of SPIE</i> , 2016, , .	0.8	5
25	Simultaneous determination of optical constants, local thickness, and local roughness of thin films by imaging spectroscopic reflectometry. , 2015, , .		0
26	Possibilities and limitations of imaging spectroscopic reflectometry in optical characterization of thin films. <i>Proceedings of SPIE</i> , 2015, , .	0.8	2
27	Measurement of optical parameters of thin films non-uniform in thickness. , 2014, , .		0
28	Measurement of thickness distribution, optical constants, and roughness parameters of rough nonuniform ZnSe thin films. <i>Applied Optics</i> , 2014, 53, 5606.	1.8	20
29	Utilization of the sum rule for construction of advanced dispersion model of crystalline silicon containing interstitial oxygen. <i>Thin Solid Films</i> , 2014, 571, 490-495.	1.8	14
30	Improved combination of scalar diffraction theory and Rayleigh-Rice theory and its application to spectroscopic ellipsometry of randomly rough surfaces. <i>Thin Solid Films</i> , 2014, 571, 695-700.	1.8	17
31	Assessment of non-uniform thin films using spectroscopic ellipsometry and imaging spectroscopic reflectometry. <i>Thin Solid Films</i> , 2014, 571, 573-578.	1.8	19
32	Ellipsometric characterization of inhomogeneous non-stoichiometric silicon nitride films. <i>Surface and Interface Analysis</i> , 2013, 45, 1188-1192.	1.8	11
33	Optical characterisation of SiO C H thin films non-uniform in thickness using spectroscopic ellipsometry, spectroscopic reflectometry and spectroscopic imaging reflectometry. <i>Thin Solid Films</i> , 2011, 519, 2874-2876.	1.8	19
34	Anisotropy-enhanced depolarization on transparent film/substrate system. <i>Thin Solid Films</i> , 2011, 519, 2637-2640.	1.8	3
35	Optical characterization of HfO ₂ thin films. <i>Thin Solid Films</i> , 2011, 519, 6085-6091.	1.8	32
36	The reflectance of non-uniform thin films. <i>Journal of Optics</i> , 2009, 11, 045202.	1.5	27

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37	Characterization of non-uniform diamond-like carbon films by spectroscopic ellipsometry. <i>Diamond and Related Materials</i> , 2009, 18, 364-367.	3.9	12
38	Complete Optical Characterization of Non-Uniform SiO _x Thin Films Using Imaging Spectroscopic Reflectometry. <i>E-Journal of Surface Science and Nanotechnology</i> , 2009, 7, 409-412.	0.4	3
39	Optical quantities of rough films calculated by Rayleigh-Rice theory. <i>Physica Status Solidi C: Current Topics in Solid State Physics</i> , 2008, 5, 1395-1398.	0.8	6
40	Optical characterization of non-stoichiometric silicon nitride films. <i>Physica Status Solidi C: Current Topics in Solid State Physics</i> , 2008, 5, 1320-1323.	0.8	4
41	Optical characterization of phase changing Ge ₂ Sb ₂ Te ₅ chalcogenide films. <i>Physica Status Solidi C: Current Topics in Solid State Physics</i> , 2008, 5, 1324-1327.	0.8	6
42	Spectroscopic ellipsometry and reflectometry of statistically rough surfaces exhibiting wide intervals of spatial frequencies. <i>Physica Status Solidi C: Current Topics in Solid State Physics</i> , 2008, 5, 1399-1402.	0.8	7
43	Optical characterization of diamond-like carbon thin films non-uniform in thickness using spectroscopic reflectometry. <i>Diamond and Related Materials</i> , 2008, 17, 709-712.	3.9	1
44	Influence of cross-correlation effects on the optical quantities of rough films. <i>Optics Express</i> , 2008, 16, 7789.	3.4	11
45	Influence of shadowing on ellipsometric quantities of randomly rough surfaces and thin films. <i>Journal of Modern Optics</i> , 2008, 55, 1077-1099.	1.3	11
46	Characterization of polymer thin films deposited on aluminum films by the combined optical method and atomic force microscopy. <i>Surface and Interface Analysis</i> , 2006, 38, 842-846.	1.8	3
47	Applications of scanning thermal microscopy in the analysis of the geometry of patterned structures. <i>Surface and Interface Analysis</i> , 2006, 38, 383-387.	1.8	14
48	Comparison of effective medium approximation and Rayleigh-Rice theory concerning ellipsometric characterization of rough surfaces. <i>Optics Communications</i> , 2005, 248, 459-467.	2.1	82
49	Atomic force microscopy analysis of morphology of the upper boundaries of GaN thin films prepared by MOCVD. <i>Vacuum</i> , 2005, 80, 53-57.	3.5	3
50	Optical characterization of thin films by the combined method of spectroscopic ellipsometry and spectroscopic photometry. <i>Vacuum</i> , 2005, 80, 159-162.	3.5	30
51	Optical characterization of double layers containing epitaxial ZnSe and ZnTe films. <i>Journal of Modern Optics</i> , 2005, 52, 583-602.	1.3	9
52	Atomic Force Microscopy Analysis of Statistical Roughness of GaAs Surfaces Originated by Thermal Oxidation. <i>Mikrochimica Acta</i> , 2004, 147, 175.	5.0	12
53	Theoretical analysis of the atomic force microscopy characterization of columnar thin films. <i>Ultramicroscopy</i> , 2003, 94, 19-29.	1.9	36
54	Atomic Force Microscopy Characterization of ZnTe Epitaxial Thin Films. <i>Japanese Journal of Applied Physics</i> , 2003, 42, 4706-4709.	1.5	13

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55	Influence of overlayers on determination of the optical constants of ZnSe thin films. Journal of Applied Physics, 2002, 92, 1873-1880.	2.5	39
56	Analysis of the boundaries of ZrO ₂ and HfO ₂ thin films by atomic force microscopy and the combined optical method. Surface and Interface Analysis, 2002, 33, 559-564.	1.8	5
57	Analysis of Slightly Rough Thin Films by Optical Methods and AFM. Mikrochimica Acta, 2000, 132, 443-447.	5.0	37
58	Ellipsometry of Thin Film Systems. Progress in Optics, 2000, 41, 181-282.	0.6	48
59	Determination of the basic parameters characterizing the roughness of metal surfaces by laser light scattering. Journal of Modern Optics, 1999, 46, 279-293.	1.3	4
60	Ellipsometric parameters and reflectances of thin films with slightly rough boundaries. Journal of Modern Optics, 1998, 45, 903-934.	1.3	68
61	IV: Scattering of Light from Multilayer Systems With Rough Boundaries. Progress in Optics, 1995, 34, 249-331.	0.6	26